

### **KSA1243**

# Power Amplifier Applications - Complement to KSC3073



## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings $\rm T_{C} = 25^{\circ}C$ unless otherwise noted

| Symbol           | Parameter                                    | Ratings    | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       | - 30       | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    | - 30       | V     |
| $V_{EBO}$        | Emitter-Base Voltage                         | - 5        | V     |
| I <sub>B</sub>   | Base Current                                 | - 0.6      | Α     |
| I <sub>C</sub>   | Collector Current                            | - 3        | Α     |
| Pc               | Collector Dissipation (T <sub>a</sub> =25°C) | 1          | W     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 10         | W     |
| T <sub>J</sub>   | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 55 ~ 150 | °C    |

### $\textbf{Electrical Characteristics} \ \textbf{T}_{\text{C}} = 25 ^{\circ} \textbf{C} \ \text{unless otherwise noted}$

| Symbol                | Parameter                            | Test Condition                                 | Min. | Тур.   | Max.  | Units |
|-----------------------|--------------------------------------|--|------|--------|-------|-------|
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown Voltage  | $I_C = -10 \text{mA}, I_B = 0$                 | - 30 |        |       | V     |
| BV <sub>EBO</sub>     | Emitter-Base Breakdown Voltage       | $I_E = -1 \text{ mA}, I_C = 0$                 | - 5  |        |       | V     |
| I <sub>CBO</sub>      | Collector Cut-off Current            | $V_{CB} = -20V, I_{E} = 0$                     |      |        | - 1   | μΑ    |
| I <sub>EBO</sub>      | Emitter Cut-off Current              | $V_{EB} = -5V, I_{C} = 0$                      |      |        | - 1   | μΑ    |
| h <sub>FE1</sub>      | DC Current Gain                      | $V_{CE} = -2V, I_{C} = -0.5A$                  | 70   |        | 240   |       |
| h <sub>FE2</sub>      |                                      | $V_{CE} = -2V, I_{C} = -2.5A$                  | 25   |        |       |       |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | I <sub>C</sub> = - 2A, I <sub>B</sub> = - 0.2A |      | - 0.3  | - 0.8 | V     |
| V <sub>BE</sub> (on)  | Base-Emitter ON Voltage              | $V_{CE} = -2V, I_{C} = -0.5A$                  |      | - 0.75 | - 1   | V     |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | $V_{CE} = -2V, I_{C} = -0.5A$                  |      | 100    |       | MHz   |
| C <sub>ob</sub>       | Output Capacitance                   | V <sub>CB</sub> = - 10V, f = 1MHz              |      | 40     |       | pF    |

### **h**<sub>FE</sub> Classification

| Classification   | 0        | Y         |  |
|------------------|----------|-----------|--|
| h <sub>FE1</sub> | 70 ~ 140 | 120 ~ 240 |  |

# **Typical Characteristics**

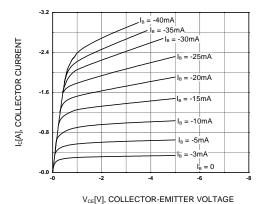


Figure 1. Static Characteristic

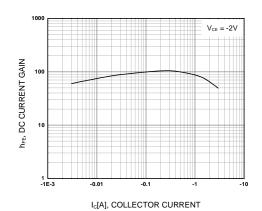


Figure 2. DC current Gain

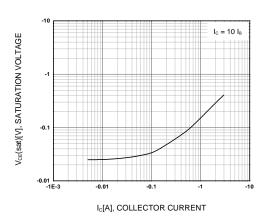


Figure 3. Collector-Emitter Saturation Votlage

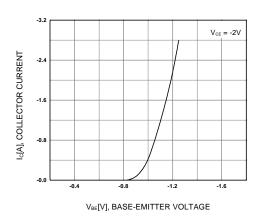


Figure 4. Base-Emitter On Voltage

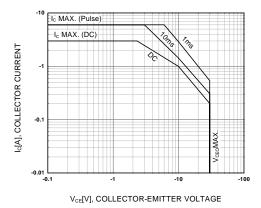


Figure 5. Safe Operating Area

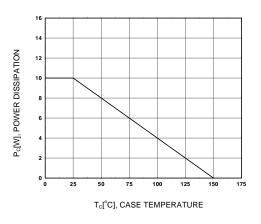
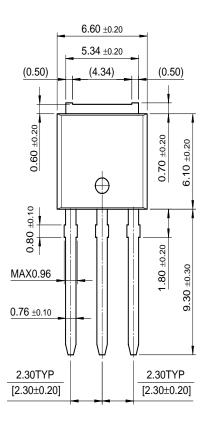


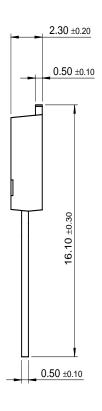
Figure 6. Power Derating

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# **Package Demensions**

# I-PAK







Dimensions in Millimeters

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